# **TEFD4300**

**Vishay Semiconductors** 



# Silicon PIN Photodiode



- Package type: leaded
- Package form: T-1
- Dimensions (in mm): Ø 3
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity:  $\phi = \pm 20^{\circ}$
- Package matched with IR emitter series VSLB3940, TSUS4300, and TSAL4400
- Material categorization: for definitions of compliance please see <a href="http://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **APPLICATIONS**

- · High speed photo detector for data transmission
- Optical switches
- Counters and sorters
- Interrupters
- Encoders
- · Position sensors

| PRODUCT SUMMARY |                      |         |                       |  |
|-----------------|----------------------|---------|-----------------------|--|
| COMPONENT       | I <sub>ra</sub> (μΑ) | φ (deg) | λ <sub>0.1</sub> (nm) |  |
| TEFD4300        | 17                   | ± 20    | 350 to 1120           |  |

#### Note

DESCRIPTION

visible and near infrared radiation.

Test condition see table "Basic Characteristics"

TEFD4300 is a silicon PIN photodiode with high radiant

sensitivity in clear, T-1 plastic package. It is sensitive to

| ORDERING INFORMATION |                   |                              |              |  |
|----------------------|-------------------|------------------------------|--------------|--|
| ORDERING CODE        | PACKAGING REMARKS |                              | PACKAGE FORM |  |
| TEFD4300             | Bulk              | MOQ: 5000 pcs, 5000 pcs/bulk | T-1          |  |

#### Note

• MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                   |             |      |
|---|--|-------------------|-------------|------|
| PARAMETER   | TEST CONDITION                               | SYMBOL            | VALUE       | UNIT |
| Reverse voltage   |  | V <sub>R</sub>    | 60          | V    |
| Power dissipation   | $T_{amb} \le 25 \ ^{\circ}C$                 | Pv                | 215         | mW   |
| Junction temperature  |  | Tj                | 100         | °C   |
| Operating temperature range   |  | T <sub>amb</sub>  | -40 to +100 | °C   |
| Storage temperature range   |  | T <sub>stg</sub>  | -40 to +100 | °C   |
| Soldering temperature   | $t \leq$ 3 s, 2 mm from case                 | T <sub>sd</sub>   | 260         | °C   |
| Thermal resistance junction/ambient   | Connected with Cu wire, 0.14 mm <sup>2</sup> | R <sub>thJA</sub> | 450         | K/W  |





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# **TEFD4300**



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| <b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                   |      |      |      |      |
|---|--|-------------------|------|------|------|------|
| PARAMETER   | TEST CONDITION   | SYMBOL            | MIN. | TYP. | MAX. | UNIT |
| Forward voltage   | I <sub>F</sub> = 50 mA   | V <sub>F</sub>    |      | 1    |      | V    |
| Breakdown voltage   | I <sub>R</sub> = 100 μA, E = 0   | V <sub>(BR)</sub> | 60   |      |      | V    |
| Reverse dark current  | V <sub>R</sub> = 10 V, E = 0   | I <sub>ro</sub>   |      | 0.15 | 3    | nA   |
| Diode capacitance   | $V_{R} = 0 V, f = 1 MHz, E = 0$  | CD                |      | 3.3  |      | pF   |
|   | V <sub>R</sub> = 5 V, f = 1 MHz, E = 0                                       | CD                |      | 1.2  |      | pF   |
| Open circuit voltage  | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$                       | V <sub>OC</sub>   |      | 350  |      | mV   |
| Temperature coefficient of Vo   | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$                       | TK <sub>Vo</sub>  |      | -2.6 |      | mV/K |
| Short circuit current   | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$                       | l <sub>k</sub>    |      | 15   |      | μA   |
| Temperature coefficient of $I_k$  | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$                       | TK <sub>lk</sub>  |      | 0.1  |      | %/K  |
| Reverse light current   | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_R = 5 \text{ V}$ | I <sub>ra</sub>   | 9    | 17   | 27   | μA   |
| Angle of half sensitivity   |  | φ                 |      | ± 20 |      | deg  |
| Wavelength of peak sensitivity  |  | λ <sub>p</sub>    |      | 950  |      | nm   |
| Range of spectral bandwidth   |  | λ <sub>0.1</sub>  | 350  |      | 1120 | nm   |
| Rise time   | $V_{R}$ = 10 V, $R_{L}$ = 1 k $\Omega$ , $\lambda$ = 820 nm                  | t <sub>r</sub>    |      | 100  |      | ns   |
| Fall time   | $V_{R}$ = 10 V, $R_{L}$ = 1 k $\Omega$ , $\lambda$ = 820 nm                  | t <sub>f</sub>    |      | 100  |      | ns   |

### BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

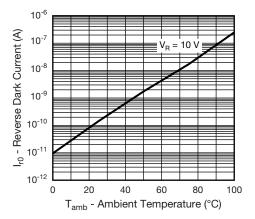


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

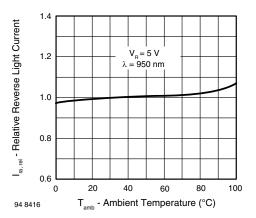


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

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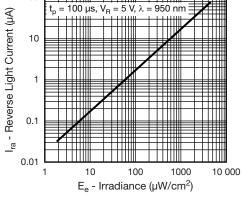


Fig. 3 - Reverse Light Current vs. Irradiance

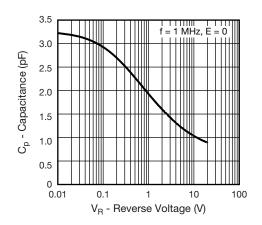


Fig. 4 - Diode Capacitance vs. Reverse Voltage

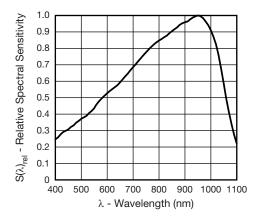


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

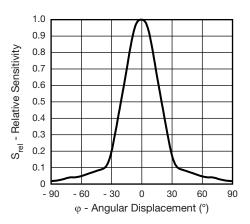


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

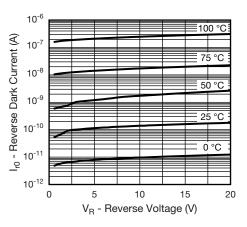


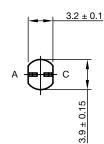
Fig. 7 - Dark Current vs. Reverse Voltage

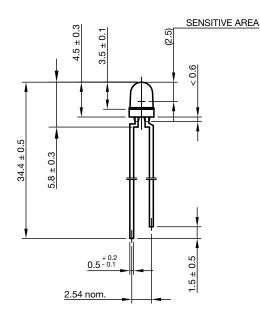
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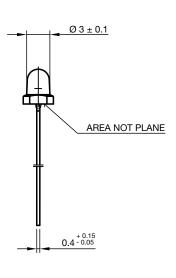


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### **PACKAGE DIMENSIONS** in millimeters









technical drawings according to DIN specifications

Drawing-No.: 6.544-5411.01-4 Issue: 2; 28.07.14



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